

IS93C56A IS93C66A

2K-BIT/4K-BIT SERIAL ELECTRICALLY ERASABLE PROM

AUGUST 2007

FEATURES

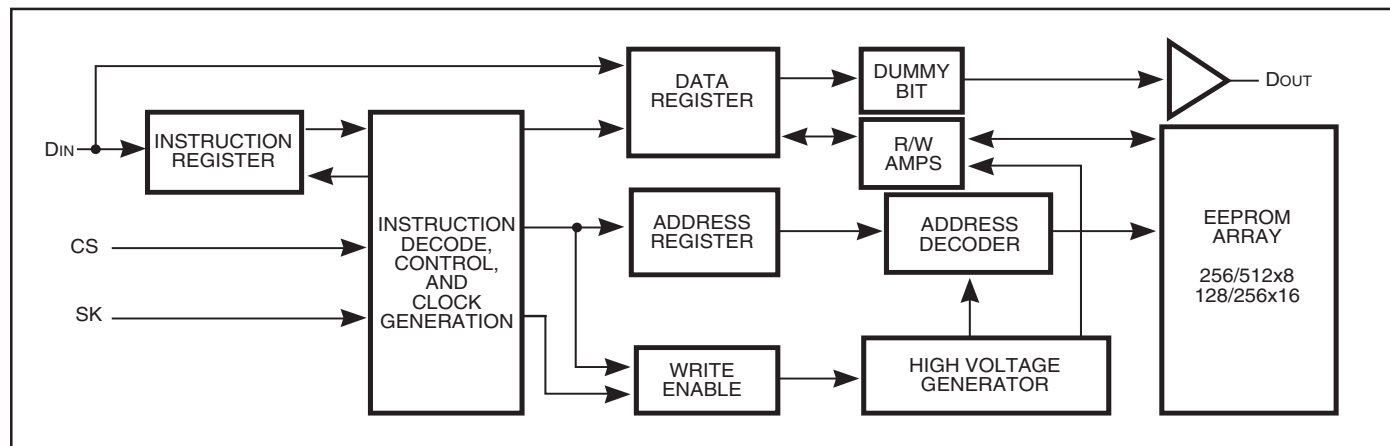
- Industry-standard Microwire Interface
 - Non-volatile data storage
 - Wide voltage operation:
 - $V_{CC} = 1.8V$ to $5.5V$
 - Auto increment for efficient data dump
- User Configured Memory Organization
 - By 16-bit or by 8-bit
- Hardware and software write protection
 - Defaults to write-disabled state at power-up
 - Software instructions for write-enable/disable
- Enhanced low voltage CMOS E²PROM technology
- Versatile, easy-to-use Interface
 - Self-timed programming cycle
 - Automatic erase-before-write
 - Programming status indicator
 - Word and chip erasable
 - Chip select enables power savings
- Durable and reliable
 - 40-year data retention after 1M write cycles
 - 1 million write cycles
 - Unlimited read cycles
 - Schmitt-trigger inputs
- Industrial and Automotive Temperature Grade
- Lead-free available

DESCRIPTION

The IS93C56A/66A are 2kb/4kb non-volatile, ISSI[®] serial EEPROMs. They are fabricated using an enhanced CMOS design and process. The IS93C56A/66A contain power-efficient read/write memory, and organization of either 256/512 bytes of 8 bits or 128/256 words of 16 bits. When the ORG pin is connected to V_{CC} or left unconnected, x16 is selected; when it is connected to ground, x8 is selected. The IS93C56A/66A are fully backward compatible with IS93C56/66.

An instruction set defines the operation of the devices, including read, write, and mode-enable functions. To protect against inadvertent data modification, all erase and write instructions are accepted only while the devices are write-enabled. A selected x8 byte or x16 word can be modified with a single WRITE or ERASE instruction. Additionally, the two instructions WRITE ALL or ERASE ALL can program an entire array. Once a device begins its self-timed program procedure, the data out pin (Dout) can indicate the READY/BUSY status by raising chip select (CS). The self-timed write cycle includes an automatic erase-before-write capability. The devices can output any number of consecutive bytes/words using a single READ instruction.

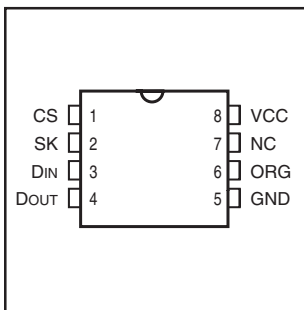
FUNCTIONAL BLOCK DIAGRAM



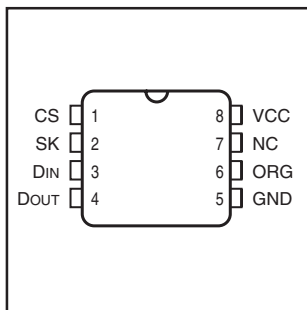
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PIN CONFIGURATIONS

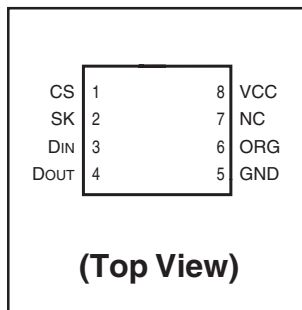
8-Pin DIP, 8-Pin TSSOP



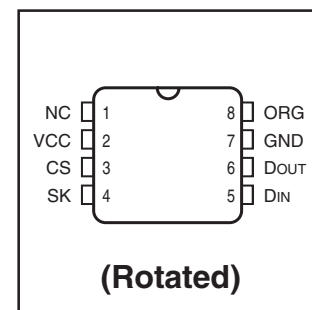
8-Pin JEDEC SOIC "GR"



8-pad DFN



8-Pin JEDEC SOIC "G"



PIN DESCRIPTIONS

| | |
|------|---------------------|
| CS | Chip Select |
| SK | Serial Data Clock |
| DIN | Serial Data Input |
| DOUT | Serial Data Output |
| ORG | Organization Select |
| NC | Not Connected |
| Vcc | Power |
| GND | Ground |

Applications

The IS93C56A/66A are very popular in many applications which require low-power, low-density storage. Applications using these devices include industrial controls, networking, and numerous other consumer electronics.

Endurance and Data Retention

The IS93C56A/66A are designed for applications requiring up to 1M programming cycles (WRITE, WRALL, ERASE and ERAL). They provide 40 years of secure data retention without power after the execution of 1M programming cycles.

Device Operations

The IS93C56A/66A are controlled by a set of instructions which are clocked-in serially on the Din pin. Before each low-to-high transition of the clock (SK), the CS pin must have already been raised to HIGH, and the Din value must be stable at either LOW or HIGH. Each

instruction begins with a start bit of the logical "1" or HIGH. Following this are the opcode (2 bits), address field (8 or 9 bits), and data, if appropriate. The clock signal may be held stable at any moment to suspend the device at its last state, allowing clock-speed flexibility. Upon completion of bus communication, CS would be pulled LOW. The device then would enter Standby mode if no internal programming is underway.

Read (READ)

The READ instruction is the only instruction that outputs serial data on the DOUT pin. After the read instruction and address have been decoded, data is transferred from the selected memory register into a serial shift register. (Please note that one logical "0" bit precedes the actual 8 or 16-bit output data string.) The output on DOUT changes during the low-to-high transitions of SK (see Figure 3).

Low Voltage Read

The IS93C56A/66A are designed to ensure that data read operations are reliable in low voltage environments. They provide accurate operation with Vcc as low as 1.8V.

Auto Increment Read Operations

In the interest of memory transfer operation applications, the IS93C56A/66A are designed to output a continuous stream of memory content in response to a single read operation instruction. To utilize this function, the system asserts a read instruction specifying a start location address. Once the 8 or 16 bits of the addressed register have been clocked out, the data in consecutively higher address locations is output. The address will wrap around continuously with CS HIGH until the chip select (CS) control pin is brought LOW. This allows for single instruction data dumps to be executed with a minimum of firmware overhead.

Write Enable (WEN)

The write enable (WEN) instruction must be executed before any device programming (WRITE, WRALL, ERASE, and ERAL) can be done. When Vcc is applied, this device powers up in the write disabled state. The device then remains in a write disabled state until a WEN instruction is executed. Thereafter, the device remains enabled until a WDS instruction is executed or until Vcc is removed. (See Figure 4.) (Note: Chip select must remain LOW until Vcc reaches its operational value.)

Write (WRITE)

The WRITE instruction includes 8 or 16 bits of data to be written into the specified register. After the last data bit has been applied to DIN, and before the next rising edge of SK, CS must be brought LOW. If the device is write-enabled, then the falling edge of CS initiates the self-timed programming cycle (see WEN).

If CS is brought HIGH, after a minimum wait of 200 ns (5V operation) after the falling edge of CS (tcs) DOUT will indicate the READY/BUSY status of the chip. Logical “0” means programming is still in progress; logical “1” means the selected register has been written, and the part is ready for another instruction (see Figure 5). The READY/BUSY status will not be available if: a) The CS input goes HIGH after the end of the self-timed programming cycle, twp; or b) Simultaneously CS is HIGH, Din is HIGH, and SK goes HIGH, which clears the status flag.

Write All (WRALL)

The write all (WRALL) instruction programs all registers with the data pattern specified in the instruction. As with the WRITE instruction, the falling edge of CS must occur to initiate the self-timed programming cycle. If CS is then brought HIGH after a minimum wait of 200 ns (tcs), the DOUT pin indicates the READY/BUSY status of the chip (see Figure 6). Vcc is required to be above 4.5V for WRALL to function properly.

Write Disable (WDS)

The write disable (WDS) instruction disables all programming capabilities. This protects the entire device against accidental modification of data until a WEN instruction is executed. (When Vcc is applied, this part powers up in the write disabled state.) To protect data, a WDS instruction should be executed upon completion of each programming operation.

Erase Register (ERASE)

After the erase instruction is entered, CS must be brought LOW. The falling edge of CS initiates the self-timed internal programming cycle. Bringing CS HIGH after a minimum of tcs, will cause DOUT to indicate the READ/BUSY status of the chip: a logical “0” indicates programming is still in progress; a logical “1” indicates the erase cycle is complete and the part is ready for another instruction (see Figure 8).

Erase All (ERALL)

Full chip erase is provided for ease of programming. Erasing the entire chip involves setting all bits in the entire memory array to a logical “1” (see Figure 9). Vcc is required to be above 4.5V for ERALL to function properly.

INSTRUCTION SET - IS93C56A (2kb)

| Instruction ⁽²⁾ | Start Bit | OP Code | 8-bit Organization (ORG = GND) | | 16-bit Organization (ORG = Vcc) | |
|-----------------------------|-----------|---------|-----------------------------------|------------|------------------------------------|------------|
| | | | Address ⁽¹⁾ | Input Data | Address ⁽¹⁾ | Input Data |
| READ | 1 | 10 | x(A7-A0) | — | x(A6-A0) | — |
| WEN (Write Enable) | 1 | 00 | 11xxxxxxx | — | 11xxxxxx | — |
| WRITE | 1 | 01 | x(A7-A0) | (D7-D0) | x(A6-A0) | (D15-D0) |
| WRALL (Write All Registers) | 1 | 00 | 01xxxxxxx | (D7-D0) | 01xxxxxx | (D15-D0) |
| WDS (Write Disable) | 1 | 00 | 00xxxxxxx | — | 00xxxxxx | — |
| ERASE | 1 | 11 | x(A7-A0) | — | x(A6-A0) | — |
| ERAL (Erase All Registers) | 1 | 00 | 10xxxxxxx | — | 10xxxxxx | — |

Notes:

1. x = Don't care bit.
2. If the number of bits clocked-in does not match the number corresponding to a selected command, all extra trailing bits are ignored, and WRITE, WRALL, ERASE, and ERAL are also ignored, but READ, WEN, WDS are accepted.

INSTRUCTION SET - IS93C66A (4kb)

| Instruction ⁽²⁾ | Start Bit | OP Code | 8-bit Organization (ORG = GND) | | 16-bit Organization (ORG = Vcc) | |
|-----------------------------|-----------|---------|-----------------------------------|------------|------------------------------------|------------|
| | | | Address ⁽¹⁾ | Input Data | Address ⁽¹⁾ | Input Data |
| READ | 1 | 10 | (A8-A0) | — | (A7-A0) | — |
| WEN (Write Enable) | 1 | 00 | 11xxxxxxx | — | 11xxxxxx | — |
| WRITE | 1 | 01 | (A8-A0) | (D7-D0) | (A7-A0) | (D15-D0) |
| WRALL (Write All Registers) | 1 | 00 | 01xxxxxxx | (D7-D0) | 01xxxxxx | (D15-D0) |
| WDS (Write Disable) | 1 | 00 | 00xxxxxxx | — | 00xxxxxx | — |
| ERASE | 1 | 11 | (A8-A0) | — | (A7-A0) | — |
| ERAL (Erase All Registers) | 1 | 00 | 10xxxxxxx | — | 10xxxxxx | — |

Notes:

1. x = Don't care bit.
2. If the number of bits clocked-in does not match the number corresponding to a selected command, all extra trailing bits are ignored, and WRITE, WRALL, ERASE, and ERAL are also ignored, but READ, WEN, WDS are accepted.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

| Symbol | Parameter | Value | Unit |
|-------------------|------------------------|-------------------------------|------|
| V _S | Supply Voltage | −0.5 to +6.5 | V |
| V _P | Voltage on Any Pin | −0.5 to V _{CC} + 0.5 | V |
| T _{BIAS} | Temperature Under Bias | −55 to +125 | °C |
| T _{STG} | Storage Temperature | −65 to +150 | °C |
| I _{OUT} | Output Current | 5 | mA |

Notes:

1. Stress greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

**OPERATING RANGE
(IS93C56A-2, IS93C66A-2)**

| Range | Ambient Temperature | V _{CC} |
|------------|---------------------|-----------------|
| Industrial | −40°C to +85°C | 1.8V to 5.5V |

Note: ISSI offers Industrial grade for Commercial applications (0°C to +70°C)

**OPERATING RANGE
(IS93C56A-3, IS93C66A-3)**

| Range | Ambient Temperature | V _{CC} |
|------------|---------------------|-----------------|
| Automotive | −40°C to +125°C | 2.5V to 5.5V |

CAPACITANCE

| Symbol | Parameter | Conditions | Max. | Unit |
|------------------|--------------------|-----------------------|------|------|
| C _{IN} | Input Capacitance | V _{IN} = 0V | 5 | pF |
| C _{OUT} | Output Capacitance | V _{OUT} = 0V | 5 | pF |

DC ELECTRICAL CHARACTERISTICS

$T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$ for Industrial and -40°C to $+125^{\circ}\text{C}$ for Automotive.

| Symbol | Parameter | Test Conditions | Vcc | Min. | Max. | Unit |
|------------------|---------------------|---|--------------|-----------------------|---------------------|---------------|
| V _{OL2} | Output LOW Voltage | I _{OL} = 100 μA | 1.8V to 2.7V | — | 0.2 | V |
| V _{OL1} | Output LOW Voltage | I _{OL} = 2.1mA | 2.7V to 5.5V | — | 0.4 | V |
| V _{OH2} | Output HIGH Voltage | I _{OH} = -100 μA | 1.8V to 2.7V | V _{CC} - 0.2 | — | V |
| V _{OH1} | Output HIGH Voltage | I _{OH} = -400 μA | 2.7V to 5.5V | 2.4 | — | V |
| V _{IH} | Input HIGH Voltage | | 1.8V to 5.5V | 0.7V _{CC} | V _{CC} +1 | V |
| V _{IL} | Input LOW Voltage | | 1.8V to 5.5V | -0.3 | 0.2xV _{CC} | V |
| I _{LI} | Input Leakage | V _{IN} = 0V to V _{CC} (CS, SK, D _{IN} , ORG) | | 0 | 2.5 | μA |
| I _{LO} | Output Leakage | V _{OUT} = 0V to V _{CC} , CS = 0V | | 0 | 2.5 | μA |

Notes:

Automotive grade devices in this table are tested with V_{CC} = 2.5V to 5.5V. An operation with V_{CC} < 2.5V is not specified.

POWER SUPPLY CHARACTERISTICS

$T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$ for Industrial, -40°C to $+125^{\circ}\text{C}$ for Automotive.

| Symbol | Parameter | Test Conditions | Vcc | Min. | Typ. | Max. | Unit |
|------------------|--------------------------------------|--|------|------|------|------|---------------|
| I _{CC1} | V _{CC} Read Supply Current | CS = V _{IH} , SK = 1 MHz, CMOS input levels | 1.8V | — | 0.1 | 1 | mA |
| | | CS = V _{IH} , SK = 2 MHz, CMOS input levels | 2.5V | — | 0.2 | 1 | mA |
| | | CS = V _{IH} , SK = 2 MHz, CMOS input levels | 5.0V | — | 0.5 | 2 | mA |
| I _{CC2} | V _{CC} Write Supply Current | CS = V _{IH} , SK = 1 MHz, CMOS input levels | 1.8V | — | 0.5 | 1 | mA |
| | | CS = V _{IH} , SK = 2 MHz, CMOS input levels | 2.5V | — | 1 | 2 | mA |
| | | CS = V _{IH} , SK = 2 MHz, CMOS input levels | 5.0V | — | 2 | 3 | mA |
| I _{SB1} | Standby Current | CS = GND, SK = GND, | 1.8V | — | 0.1 | 1 | μA |
| | | ORG = V _{CC} or Floating (x16) | 2.5V | — | 0.1 | 2 | μA |
| | | | 5.0V | — | 0.2 | 4 | μA |
| I _{SB2} | Standby Current | CS = GND, SK = GND, | 1.8V | — | 6 | 10 | μA |
| | | ORG = GND (x8) | 2.5V | — | 6 | 10 | μA |
| | | | 5.0V | — | 10 | 15 | μA |

AC ELECTRICAL CHARACTERISTICS

T_A = -40°C to +85°C for Industrial

| Symbol | Parameter | Test Conditions | Min. | Max. | Unit | |
|------------------|-----------------------|-------------------------------|-------------------------------|------|------|----|
| f _{SK} | SK Clock Frequency | 1.8V ≤ V _{CC} < 2.5V | 0 | 1 | Mhz | |
| | | 2.5V ≤ V _{CC} < 4.5V | 0 | 2 | Mhz | |
| | | 4.5V ≤ V _{CC} ≤ 5.5V | 0 | 3 | Mhz | |
| t _{SKH} | SK HIGH Time | 1.8V ≤ V _{CC} < 2.5V | 250 | — | ns | |
| | | 2.5V ≤ V _{CC} < 4.5V | 200 | — | ns | |
| | | 4.5V ≤ V _{CC} ≤ 5.5V | 200 | — | ns | |
| t _{SKL} | SK LOW Time | 1.8V ≤ V _{CC} < 2.5V | 250 | — | ns | |
| | | 2.5V ≤ V _{CC} < 4.5V | 200 | — | ns | |
| | | 4.5V ≤ V _{CC} ≤ 5.5V | 100 | — | ns | |
| t _{CS} | Minimum CS LOW Time | 1.8V ≤ V _{CC} < 2.5V | 250 | — | ns | |
| | | 2.5V ≤ V _{CC} < 4.5V | 200 | — | ns | |
| | | 4.5V ≤ V _{CC} ≤ 5.5V | 200 | — | ns | |
| t _{CSS} | CS Setup Time | Relative to SK | 1.8V ≤ V _{CC} < 2.5V | 200 | — | ns |
| | | 2.5V ≤ V _{CC} < 4.5V | 100 | — | ns | |
| | | 4.5V ≤ V _{CC} ≤ 5.5V | 50 | — | ns | |
| t _{DIS} | Din Setup Time | Relative to SK | 1.8V ≤ V _{CC} < 2.5V | 100 | — | ns |
| | | 2.5V ≤ V _{CC} < 4.5V | 50 | — | ns | |
| | | 4.5V ≤ V _{CC} ≤ 5.5V | 50 | — | ns | |
| t _{CSH} | CS Hold Time | Relative to SK | 1.8V ≤ V _{CC} < 2.5V | 0 | — | ns |
| | | 2.5V ≤ V _{CC} < 4.5V | 0 | — | ns | |
| | | 4.5V ≤ V _{CC} ≤ 5.5V | 0 | — | ns | |
| t _{DIH} | Din Hold Time | Relative to SK | 1.8V ≤ V _{CC} < 2.5V | 50 | — | ns |
| | | 2.5V ≤ V _{CC} < 4.5V | 50 | — | ns | |
| | | 4.5V ≤ V _{CC} ≤ 5.5V | 50 | — | ns | |
| t _{PD1} | Output Delay to “1” | AC Test | 1.8V ≤ V _{CC} < 2.5V | — | 400 | ns |
| | | 2.5V ≤ V _{CC} < 4.5V | — | 200 | ns | |
| | | 4.5V ≤ V _{CC} ≤ 5.5V | — | 100 | ns | |
| t _{PD0} | Output Delay to “0” | AC Test | 1.8V ≤ V _{CC} < 2.5V | — | 400 | ns |
| | | 2.5V ≤ V _{CC} < 4.5V | — | 200 | ns | |
| | | 4.5V ≤ V _{CC} ≤ 5.5V | — | 100 | ns | |
| t _{SV} | CS to Status Valid | AC Test | 1.8V ≤ V _{CC} < 2.5V | — | 400 | ns |
| | | 2.5V ≤ V _{CC} < 4.5V | — | 200 | ns | |
| | | 4.5V ≤ V _{CC} ≤ 5.5V | — | 200 | ns | |
| t _{DF} | CS to Dout in 3-state | AC Test, CS=VIL | 1.8V ≤ V _{CC} < 2.5V | — | 100 | ns |
| | | 2.5V ≤ V _{CC} < 4.5V | — | 100 | ns | |
| | | 4.5V ≤ V _{CC} ≤ 5.5V | — | 100 | ns | |
| t _{WP} | Write Cycle Time | 1.8V ≤ V _{CC} < 2.5V | — | 10 | ms | |
| | | 2.5V ≤ V _{CC} < 4.5V | — | 5 | ms | |
| | | 4.5V ≤ V _{CC} ≤ 5.5V | — | 5 | ms | |

Notes:

1. C_L = 100pF

AC ELECTRICAL CHARACTERISTICS

TA = -40°C to +125°C for Automotive

| Symbol | Parameter | Test Conditions | Min. | Max. | Unit | |
|------------------|-----------------------|-------------------------------|-------------------------------|------|------|----|
| f _{SK} | SK Clock Frequency | 2.5V ≤ V _{CC} < 4.5V | 0 | 2 | Mhz | |
| | | 4.5V ≤ V _{CC} ≤ 5.5V | 0 | 3 | Mhz | |
| t _{SKH} | SK HIGH Time | 2.5V ≤ V _{CC} < 4.5V | 200 | — | ns | |
| | | 4.5V ≤ V _{CC} ≤ 5.5V | 200 | — | ns | |
| t _{SKL} | SK LOW Time | 2.5V ≤ V _{CC} < 4.5V | 200 | — | ns | |
| | | 4.5V ≤ V _{CC} ≤ 5.5V | 100 | — | ns | |
| t _{CS} | Minimum CS LOW Time | 2.5V ≤ V _{CC} < 4.5V | 200 | — | ns | |
| | | 4.5V ≤ V _{CC} ≤ 5.5V | 200 | — | ns | |
| t _{CSS} | CS Setup Time | Relative to SK | 2.5V ≤ V _{CC} < 4.5V | 100 | — | ns |
| | | | 4.5V ≤ V _{CC} ≤ 5.5V | 50 | — | ns |
| t _{DIS} | Din Setup Time | Relative to SK | 2.5V ≤ V _{CC} < 4.5V | 50 | — | ns |
| | | | 4.5V ≤ V _{CC} ≤ 5.5V | 50 | — | ns |
| t _{CSH} | CS Hold Time | Relative to SK | 2.5V ≤ V _{CC} < 4.5V | 0 | — | ns |
| | | | 4.5V ≤ V _{CC} ≤ 5.5V | 0 | — | ns |
| t _{DIH} | Din Hold Time | Relative to SK | 2.5V ≤ V _{CC} < 4.5V | 50 | — | ns |
| | | | 4.5V ≤ V _{CC} ≤ 5.5V | 50 | — | ns |
| t _{PD1} | Output Delay to “1” | AC Test | 2.5V ≤ V _{CC} < 4.5V | — | 200 | ns |
| | | | 4.5V ≤ V _{CC} ≤ 5.5V | — | 100 | ns |
| t _{PD0} | Output Delay to “0” | AC Test | 2.5V ≤ V _{CC} < 4.5V | — | 200 | ns |
| | | | 4.5V ≤ V _{CC} ≤ 5.5V | — | 100 | ns |
| t _{SV} | CS to Status Valid | AC Test | 2.5V ≤ V _{CC} < 4.5V | — | 200 | ns |
| | | | 4.5V ≤ V _{CC} ≤ 5.5V | — | 200 | ns |
| t _{DF} | CS to Dout in 3-state | AC Test, CS=VIL | 2.5V ≤ V _{CC} < 4.5V | — | 100 | ns |
| | | | 4.5V ≤ V _{CC} ≤ 5.5V | — | 100 | ns |
| t _{WP} | Write Cycle Time | | 2.5V ≤ V _{CC} < 4.5V | — | 5 | ms |
| | | | 4.5V ≤ V _{CC} ≤ 5.5V | — | 5 | ms |

Notes:

1. C_L = 100pF

AC WAVEFORMS

FIGURE 2. SYNCHRONOUS DATA TIMING

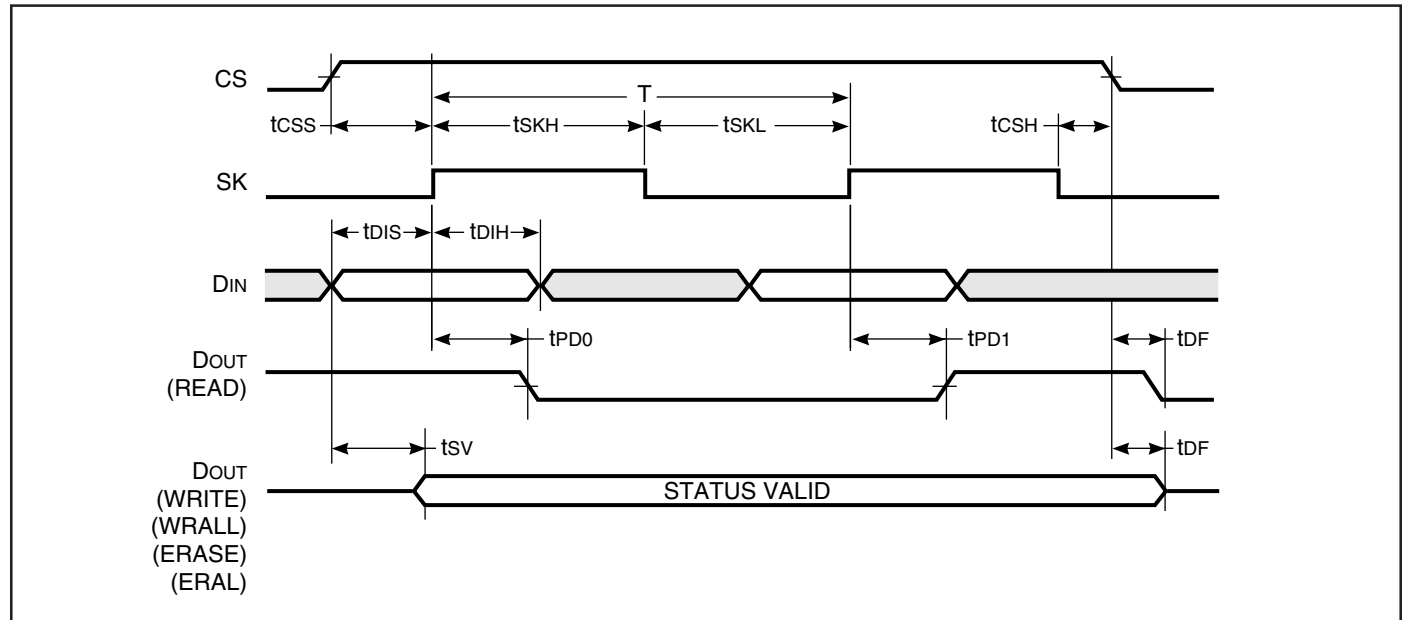
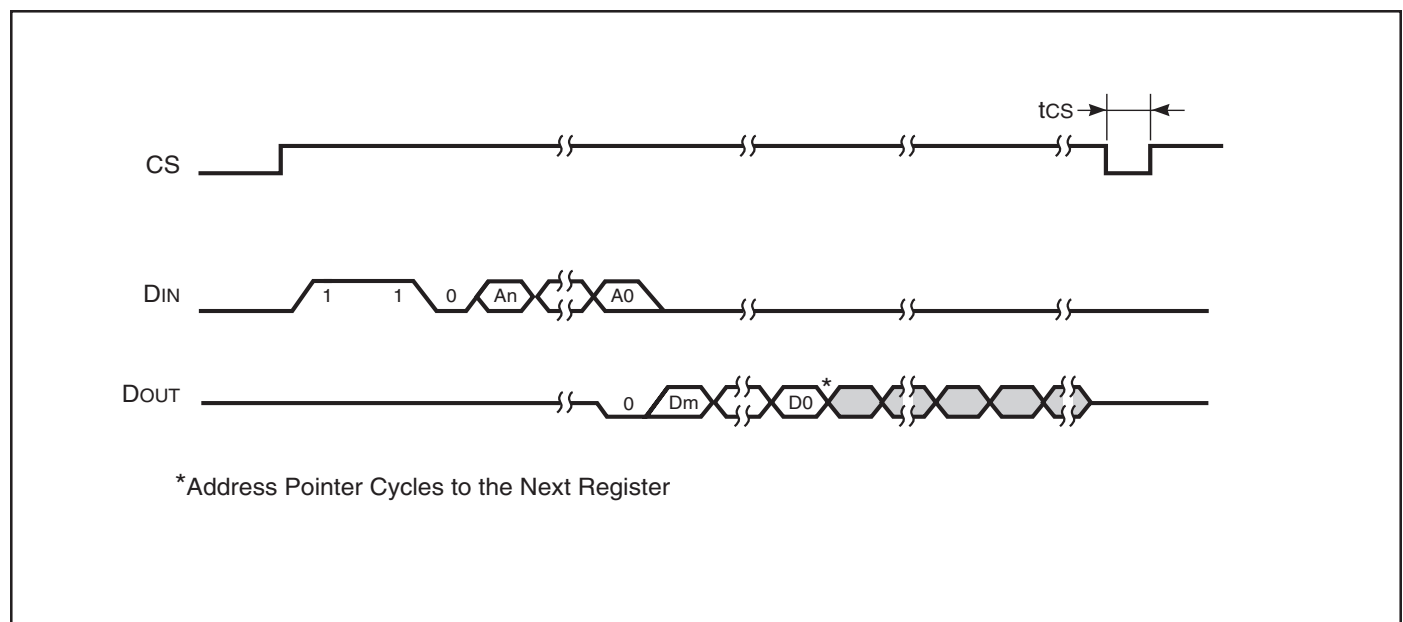


FIGURE 3. READ CYCLE TIMING



Notes:

To determine address bits A_n - A_0 and data bits D_m - D_0 , see Instruction Set for the specific device.

AC WAVEFORMS

FIGURE 4. WRITE ENABLE (WEN) CYCLE TIMING

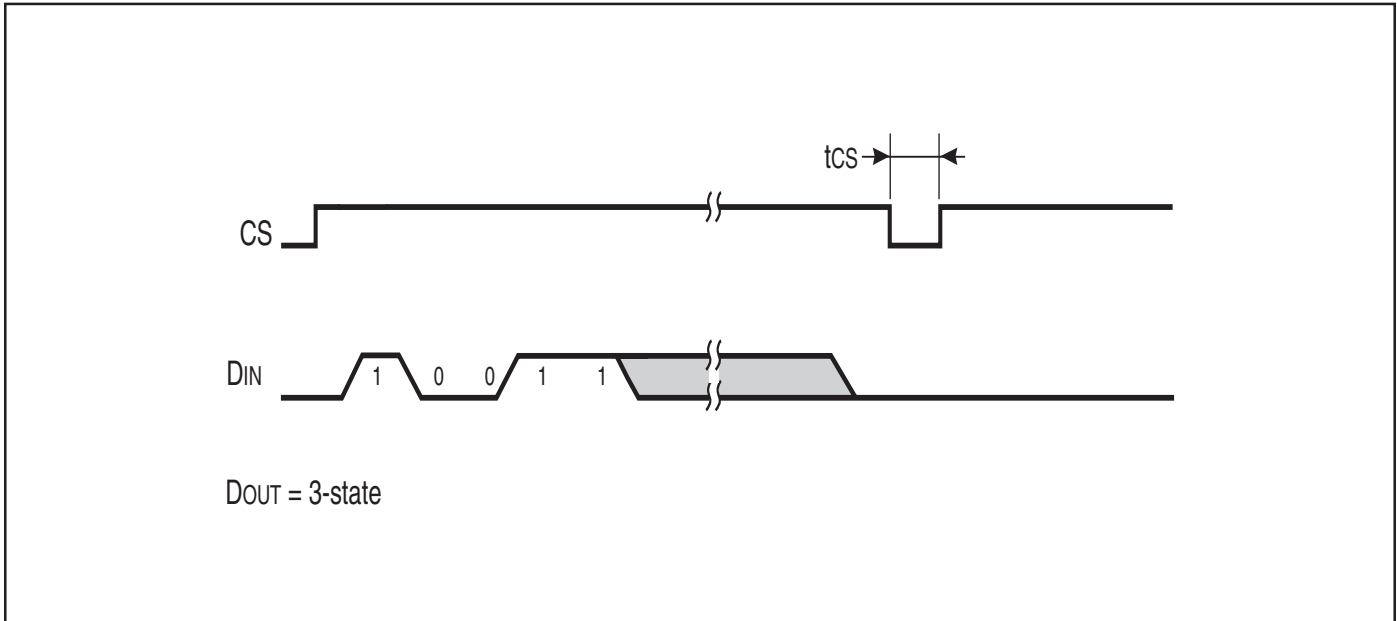
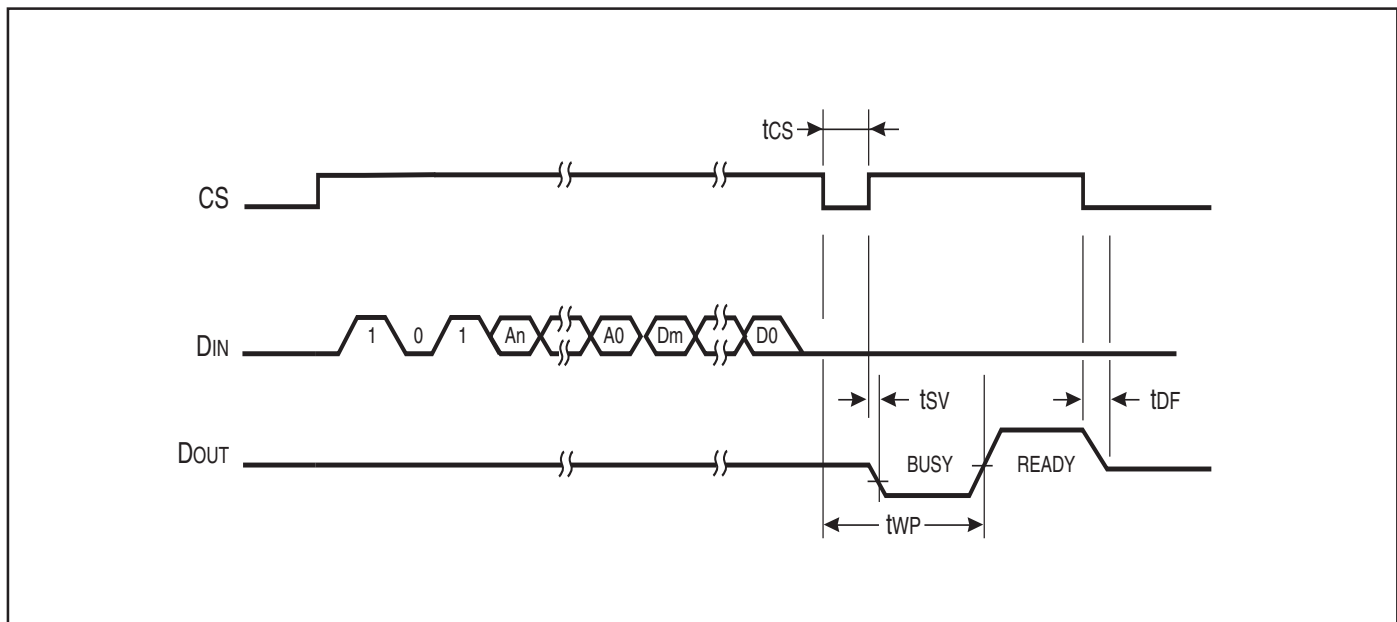


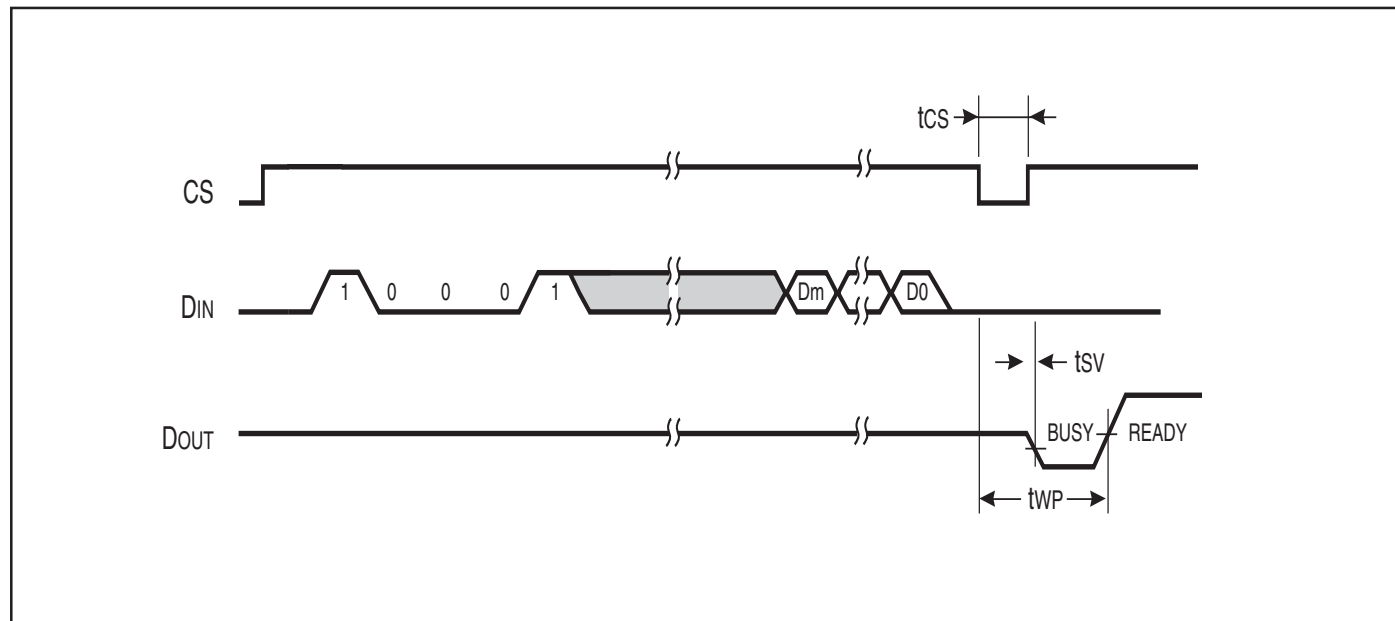
FIGURE 5. WRITE (WRITE) CYCLE TIMING

**Notes:**

1. After the completion of the instruction (DOUT is in READY status) then it may perform another instruction. If device is in **BUSY** status (DOUT indicates **BUSY** status) then attempting to perform another instruction could cause device malfunction.
2. To determine address bits A_n - A_0 and data bits D_m - D_0 , see Instruction Set for the specific device.

AC WAVEFORMS

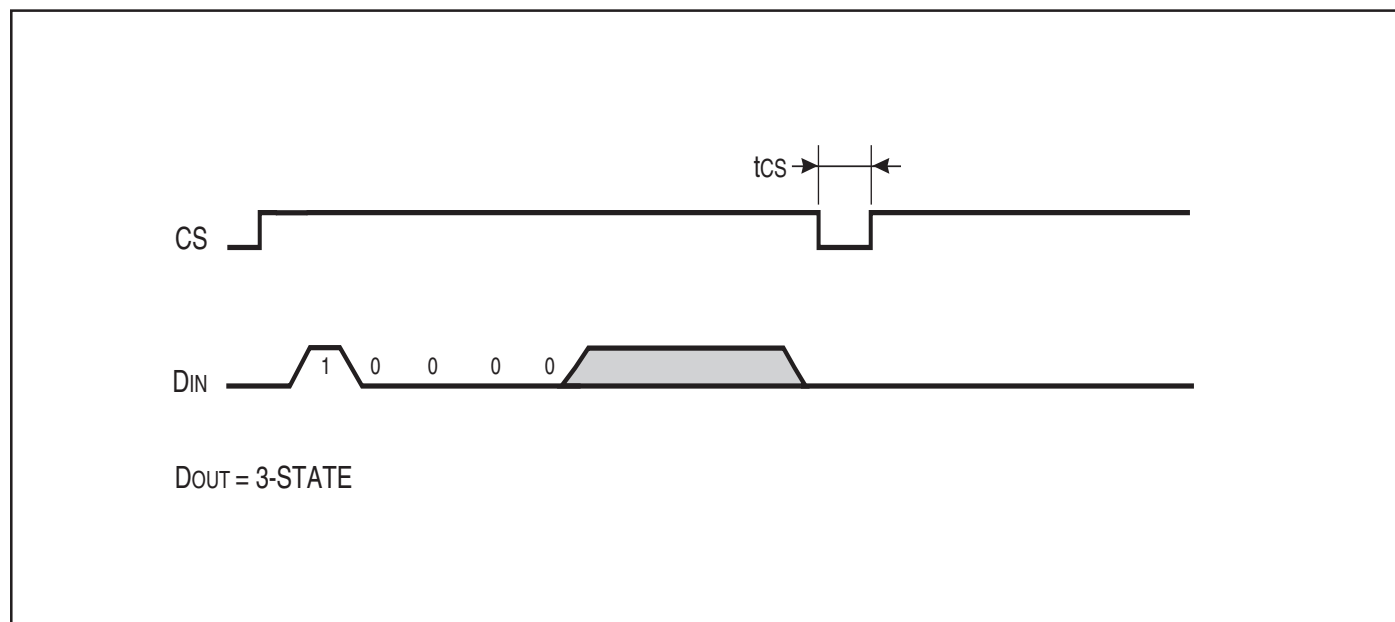
FIGURE 6. WRITE ALL (WRALL) CYCLE TIMING



Notes:

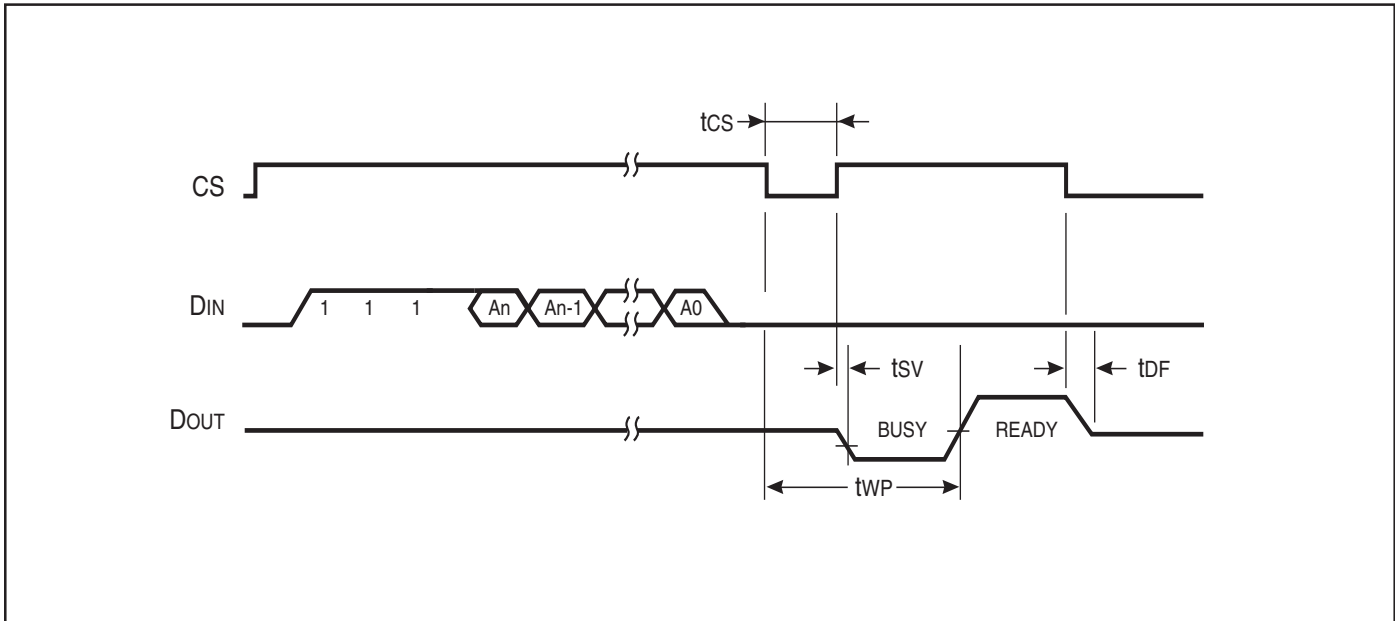
1. After the completion of the instruction (DOUT is in READY status) then it may perform another instruction. If device is in **BUSY** status (DOUT indicates **BUSY** status) then attempting to perform another instruction could cause device malfunction.
2. To determine data bits D_m - D_0 , see Instruction Set for the appropriate device.

FIGURE 7. WRITE DISABLE (WDS) CYCLE TIMING



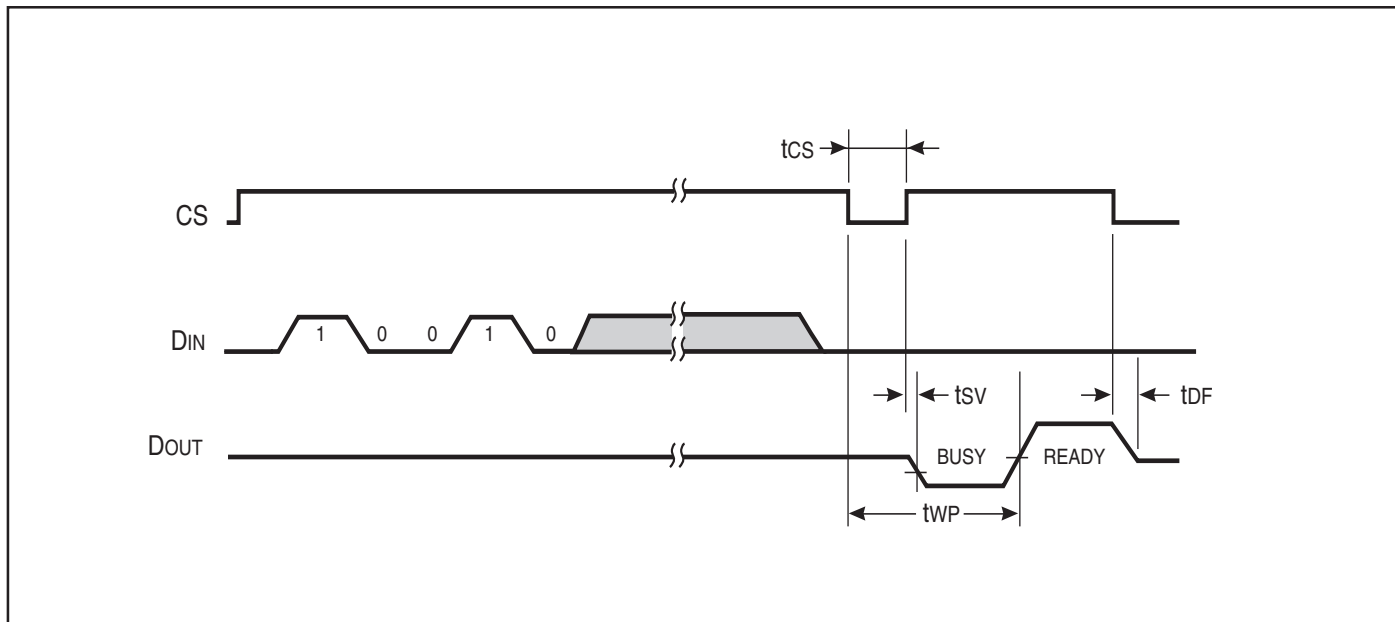
AC WAVEFORMS

FIGURE 8. ERASE (REGISTER ERASE) CYCLE TIMING

**Notes:**

To determine data bits $A_n - A_0$, see Instruction Set for the appropriate device.

FIGURE 9. ERASE ALL (ERAL) CYCLE TIMING

**Note for Figures 8 and 9:**

After the completion of the instruction (DOUT is in READY status) then it may perform another instruction. If device is in **BUSY** status (DOUT indicates **BUSY** status) then attempting to perform another instruction could cause device malfunction.

ORDERING INFORMATION

Industrial Range: -40°C to +85°C

| Voltage Range | Order Part No. | Package |
|---------------|----------------|---------------------|
| 1.8V to 5.5V | IS93C56A-2PI | 300-mil Plastic DIP |
| | IS93C56A-2GRI | SOIC JEDEC |
| | IS93C56A-2ZI | 169-mil TSSOP |
| 1.8V to 5.5V | IS93C66A-2PI | 300-mil Plastic DIP |
| | IS93C66A-2GRI | SOIC JEDEC |
| | IS93C66A-2ZI | 169-mil TSSOP |

Automotive Range: -40°C to +125°C, Lead-free

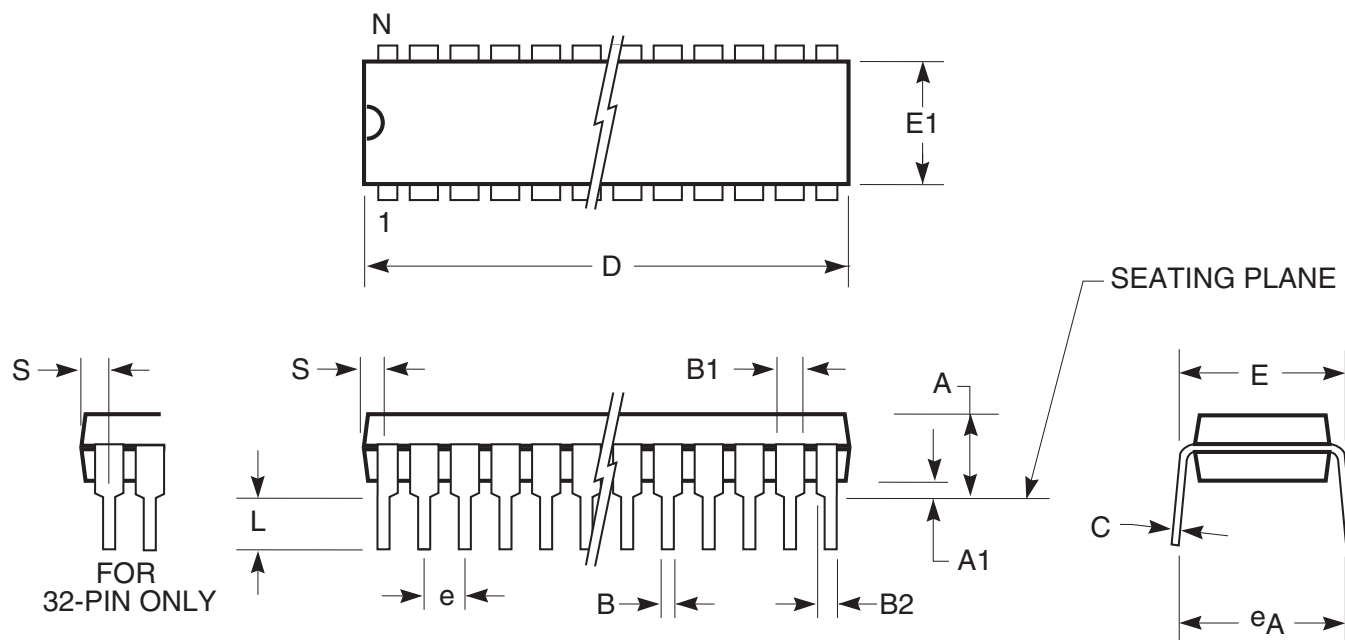
| Voltage Range | Order Part No. | Package |
|---------------|-----------------|---------------------|
| 2.5V to 5.5V | IS93C56A-3PLA3 | 300-mil Plastic DIP |
| | IS93C56A-3GRLA3 | SOIC JEDEC |
| | IS93C56A-3ZLA3 | 169-mil TSSOP |
| 2.5V to 5.5V | IS93C66A-3PLA3 | 300-mil Plastic DIP |
| | IS93C66A-3GRLA3 | SOIC JEDEC |
| | IS93C66A-3ZLA3 | 169-mil TSSOP |

Industrial Range: -40°C to +85°C, Lead-free

| Voltage Range | Order Part No. | Package |
|---------------|----------------|---------------------|
| 1.8V to 5.5V | IS93C56A-2PLI | 300-mil Plastic DIP |
| | IS93C56A-2DLI | 8-pad DFN |
| | IS93C56A-2GLI | SOIC JEDEC |
| | IS93C56A-2GRLI | SOIC JEDEC |
| | IS93C56A-2ZLI | 169-mil TSSOP |
| 1.8V to 5.5V | IS93C66A-2PLI | 300-mil Plastic DIP |
| | IS93C66A-2DLI | 8-pad DFN |
| | IS93C66A-2GRLI | SOIC JEDEC |
| | IS93C66A-2ZLI | 169-mil TSSOP |

PACKAGING INFORMATION

300-mil Plastic DIP
Package Code: N,P



| | MILLIMETERS | | INCHES | |
|--------------|-------------|-------|-----------|-------|
| Sym. | Min. | Max. | Min. | Max. |
| N0. Leads | 8 | | | |
| A | 3.68 | 4.57 | 0.145 | 0.180 |
| A1 | 0.38 | — | 0.015 | — |
| B | 0.36 | 0.56 | 0.014 | 0.022 |
| B1 | 1.14 | 1.52 | 0.045 | 0.060 |
| B2 | 0.81 | 1.17 | 0.032 | 0.046 |
| C | 0.20 | 0.33 | 0.008 | 0.013 |
| D | 9.12 | 9.53 | 0.359 | 0.375 |
| E | 7.62 | 8.26 | 0.300 | 0.325 |
| E1 | 6.20 | 6.60 | 0.244 | 0.260 |
| eA | 8.13 | 9.65 | 0.320 | 0.380 |
| e | 2.54 BSC | | 0.100 BSC | |
| L | 3.18 | — | 0.125 | — |
| S | 0.64 | 0.762 | 0.025 | 0.030 |

Notes:

1. Controlling dimension: inches, unless otherwise specified.
2. BSC = Basic lead spacing between centers.
3. Dimensions D and E1 do not include mold flash protrusions and should be measured from the bottom of the package.
4. Formed leads shall be planar with respect to one another within 0.004 inches at the seating plane.

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Rev. D
02/14/03

PACKAGING INFORMATION

300-mil Plastic DIP Package Code: N,P

| MILLIMETERS | | | INCHES | |
|--------------|-----------|-------|-----------|-------|
| Sym. | Min. | Max. | Min. | Max. |
| N0. Leads | 16 | | | |
| A | 3.68 | 4.57 | 0.145 | 0.180 |
| A1 | 0.25 | — | 0.010 | — |
| B | 0.46 BSC | | 0.018 BSC | |
| B1 | 1.52 BSC | | 0.060 BSC | |
| B2 | — | — | — | — |
| C | 0.13 | 0.38 | 0.005 | 0.015 |
| D | 18.92 | 19.18 | 0.745 | 0.755 |
| E | 7.44 | 8.13 | 0.293 | 0.320 |
| E1 | 6.22 | 6.48 | 0.245 | 0.255 |
| eA | 8.13 | 9.65 | 0.320 | 0.380 |
| e | 2.54 BSC | | 0.100 BSC | |
| L | 3.05 | 3.56 | 0.120 | 0.140 |
| S | 0.38 | 0.89 | 0.015 | 0.035 |

| MILLIMETERS | | | INCHES | |
|--------------|-----------|-------|-----------|-------|
| Sym. | Min. | Max. | Min. | Max. |
| N0. Leads | 28 | | | |
| A | 3.68 | 4.57 | 0.145 | 0.180 |
| A1 | 0.25 | — | 0.010 | — |
| B | 0.41 | 0.56 | 0.016 | 0.022 |
| B1 | 1.27 | 1.78 | 0.050 | 0.070 |
| B2 | 0.81 | 1.17 | 0.032 | 0.046 |
| C | 0.20 | 0.38 | 0.008 | 0.015 |
| D | 35.05 | 35.56 | 1.380 | 1.400 |
| E | 7.49 | 8.00 | 0.295 | 0.315 |
| E1 | 6.99 | 7.49 | 0.275 | 0.295 |
| eA | 7.87 | 10.16 | 0.310 | 0.400 |
| e | 2.54 BSC | | 0.100 BSC | |
| L | 3.05 | 3.81 | 0.120 | 0.150 |
| S | 0.51 | 1.06 | 0.020 | 0.042 |

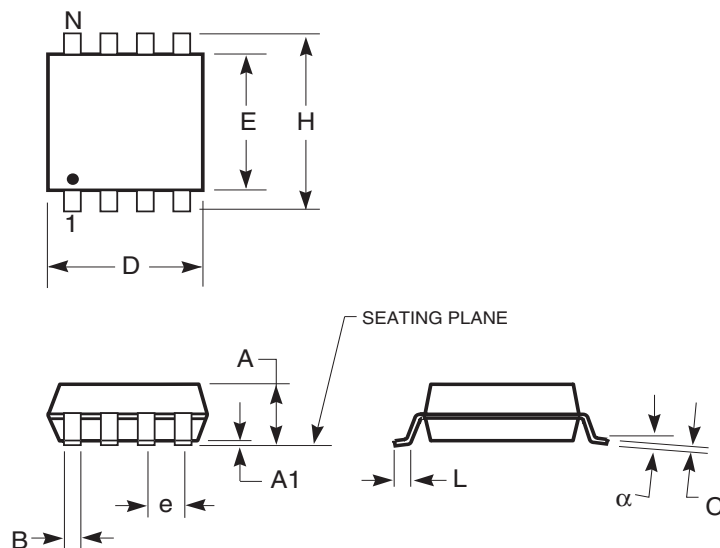
| MILLIMETERS | | | INCHES | |
|--------------|-----------|-------|-----------|-------|
| Sym. | Min. | Max. | Min. | Max. |
| N0. Leads | 20 | | | |
| A | 3.68 | 4.57 | 0.145 | 0.180 |
| A1 | 0.38 | — | 0.015 | — |
| B | 0.36 | 0.56 | 0.014 | 0.022 |
| B1 | 1.14 | 1.78 | 0.045 | 0.070 |
| B2 | — | — | — | — |
| C | 0.20 | 0.36 | 0.008 | 0.014 |
| D | 25.91 | 26.42 | 1.020 | 1.040 |
| E | 7.49 | 8.26 | 0.295 | 0.325 |
| E1 | 6.01 | 7.11 | 0.240 | 0.280 |
| eA | — | 10.92 | — | 0.430 |
| e | 2.54 BSC | | 0.100 BSC | |
| L | 3.05 | 3.81 | 0.120 | 0.150 |
| S | 1.02 | 1.52 | 0.040 | 0.060 |

| MILLIMETERS | | | INCHES | |
|--------------|-----------|-------|-----------|-------|
| Sym. | Min. | Max. | Min. | Max. |
| N0. Leads | 32 | | | |
| A | 3.56 | 4.57 | 0.140 | 0.180 |
| A1 | 0.38 | — | 0.015 | — |
| B | 0.38 | 0.53 | 0.015 | 0.021 |
| B1 | 1.02 | 1.78 | 0.040 | 0.070 |
| B2 | — | — | — | — |
| C | 0.13 | 0.38 | 0.005 | 0.015 |
| D | 40.51 | 40.77 | 1.595 | 1.605 |
| E | 7.75 | 8.26 | 0.305 | 0.325 |
| E1 | 7.24 | 7.22 | 0.285 | 0.292 |
| eA | 8.38 | 9.40 | 0.33 | 0.370 |
| e | 2.54 BSC | | 0.100 BSC | |
| L | 3.05 | 3.81 | 0.120 | 0.150 |
| S | 1.65 | 2.16 | 0.065 | 0.085 |

PACKAGING INFORMATION

150-mil Plastic SOP

Package Code: G, GR



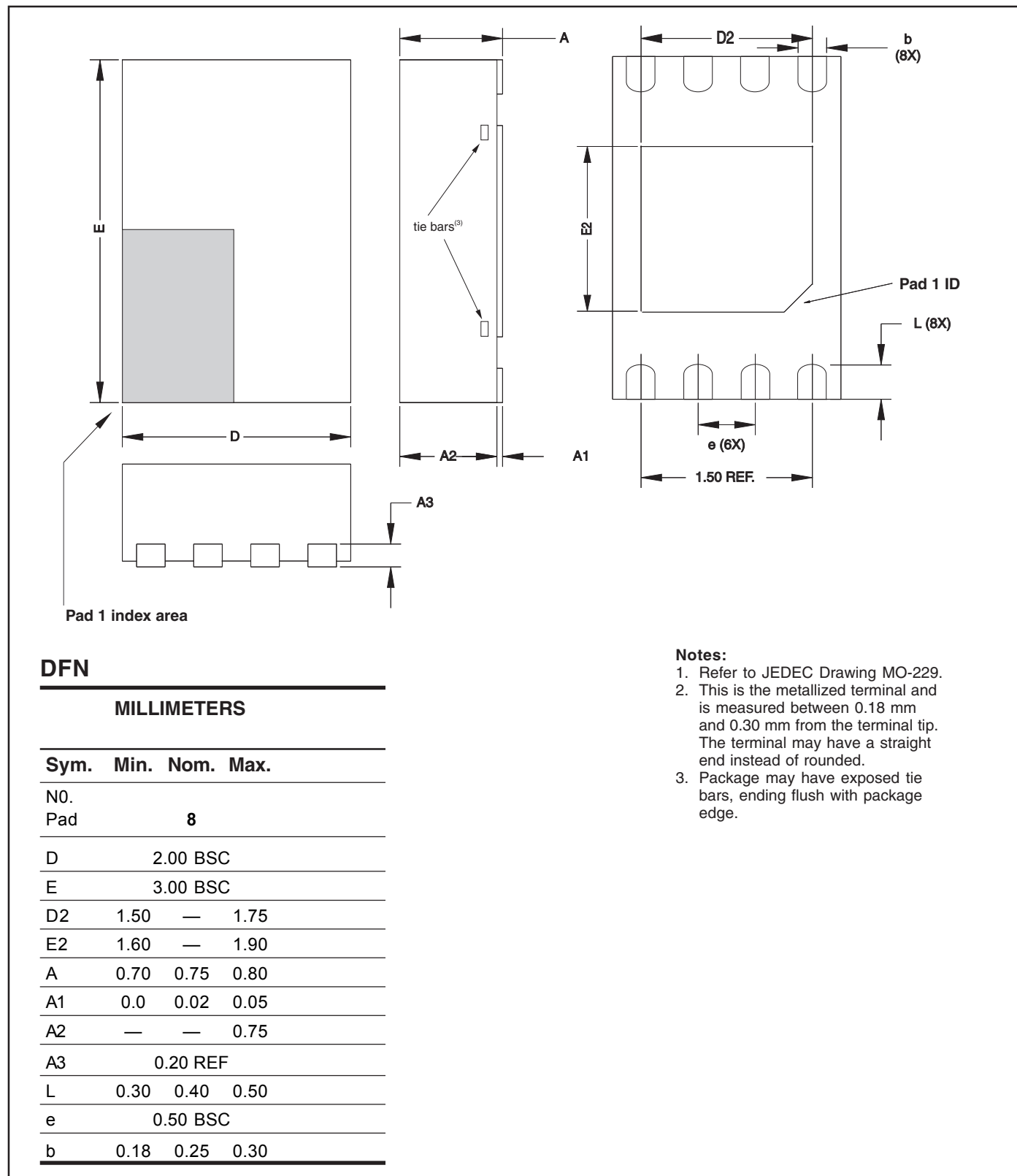
| 150-mil Plastic SOP (G, GR) | | | | |
|-----------------------------|-----------|-------|----------|------|
| Symbol | Min | Max | Min | Max |
| Ref. Std. | Inches | | mm | |
| No. Leads | 8 | | 8 | |
| A | — | 0.068 | — | 1.73 |
| A1 | 0.004 | 0.009 | 0.1 | 0.23 |
| B | 0.013 | 0.020 | 0.33 | 0.51 |
| C | 0.007 | 0.010 | 0.18 | 0.25 |
| D | 0.189 | 0.197 | 4.8 | 5 |
| E | 0.150 | 0.157 | 3.81 | 3.99 |
| H | 0.228 | 0.245 | 5.79 | 6.22 |
| e | 0.050 BSC | | 1.27 BSC | |
| L | 0.020 | 0.035 | 0.51 | 0.89 |

Notes:

1. Controlling dimension: inches, unless otherwise specified.
2. BSC = Basic lead spacing between centers.
3. Dimensions D and E1 do not include mold flash protrusions and should be measured from the bottom of the package.
4. Formed leads shall be planar with respect to one another within 0.004 inches at the seating plane.

PACKAGING INFORMATION

Dual Flat No-Lead
Package Code: D (8-pad)



Notes:

1. Refer to JEDEC Drawing MO-229.
2. This is the metallized terminal and is measured between 0.18 mm and 0.30 mm from the terminal tip. The terminal may have a straight end instead of rounded.
3. Package may have exposed tie bars, ending flush with package edge.

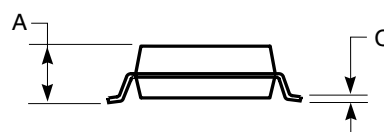
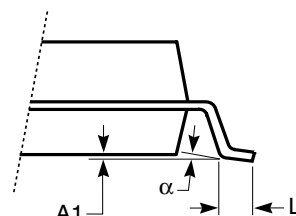
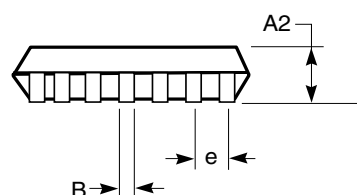
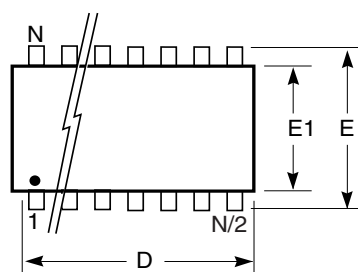
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Rev. B
02/13/06

PACKAGING INFORMATION

Thin Shrink Small Outline TSSOP
Package Code: Z (8 pin, 14 pin)



| TSSOP (Z) | | | | |
|-----------|--------------|------|-----------|-------|
| Ref. Std. | JEDEC MO-153 | | | |
| No. Leads | 8 | | | |
| | Millimeters | | Inches | |
| Symbol | Min | Max | Min | Max |
| A | — | 1.20 | — | 0.047 |
| A1 | 0.05 | 0.15 | 0.002 | 0.006 |
| A2 | 0.80 | 1.05 | 0.032 | 0.041 |
| B | 0.19 | 0.30 | 0.007 | 0.012 |
| C | 0.09 | 0.20 | 0.004 | 0.008 |
| D | 2.90 | 3.10 | 0.114 | 0.122 |
| E1 | 4.30 | 4.50 | 0.169 | 0.177 |
| E | 6.40 BSC | | 0.252 BSC | |
| e | 0.65 BSC | | 0.026 BSC | |
| L | 0.45 | 0.75 | 0.018 | 0.030 |
| α | — | 8° | — | 8° |

| TSSOP (Z) | | | | |
|-----------|--------------|------|-----------|--------|
| Ref. Std. | JEDEC MO-153 | | | |
| No. Leads | 14 | | | |
| | Millimeters | | Inches | |
| Symbol | Min | Max | Min | Max |
| A | — | 1.20 | — | 0.047 |
| A1 | 0.05 | 0.15 | 0.002 | 0.006 |
| A2 | 0.80 | 1.05 | 0.031 | 0.041 |
| B | 0.19 | 0.30 | 0.007 | 0.012 |
| C | 0.09 | 0.20 | 0.0035 | 0.008 |
| D | 4.90 | 5.10 | 0.193 | 0.201 |
| E1 | 4.30 | 4.50 | 0.170 | 0.177 |
| E | 6.40 BSC | | 0.252 BSC | |
| e | 0.65 BSC | | 0.026 BSC | |
| L | 0.45 | 0.75 | 0.0177 | 0.0295 |
| α | — | 8° | — | 8° |

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